

FEATURES

High common-mode voltage range

4 V to 80 V operating
–0.3 V to +85 V survival

Buffered output voltage

Gain = 60 V/V

Wide operating temperature range: –40°C to +125°C

Excellent ac and dc performance

±100 nV/°C typical offset drift
±50 µV typical offset
±5 ppm/°C typical gain drift
110 dB typical CMRR at dc

APPLICATIONS

High-side current sensing

48 V telecom
Power management
Base stations
Unidirectional motor control
Precision high voltage current sources

GENERAL DESCRIPTION

The AD8219 is a high voltage, high resolution, current shunt amplifier. It features a set gain of 60 V/V, with a maximum ±0.3% gain error over the entire temperature range. The buffered output voltage directly interfaces with any typical converter. The AD8219 offers excellent input common-mode rejection from 4 V to 80 V. The AD8219 performs unidirectional current measurements across a shunt resistor in a variety of industrial and telecom applications including motor control, power management, and base station power amplifier bias control.

FUNCTIONAL BLOCK DIAGRAM

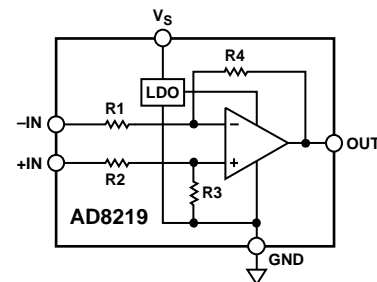


Figure 1.

08415-001

The AD8219 offers breakthrough performance throughout the –40°C to +125°C temperature range. It features a zero drift core, which leads to a typical offset drift of ±100 nV/°C throughout the operating temperature and common-mode voltage range. Special attention is devoted to output linearity being maintained throughout the input differential voltage range, regardless of the common-mode voltage present, while the typical input offset voltage is ±50 µV.

The AD8219 is offered in a 8-lead MSOP package.

Rev. A

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

AD8219* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

DOCUMENTATION

Data Sheet

- AD8219: Zero Drift, Unidirectional Current Shunt Monitor Data Sheet

TOOLS AND SIMULATIONS

- AD8219 SPICE Macro Model

DESIGN RESOURCES

- AD8219 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all AD8219 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

TABLE OF CONTENTS

Features	1	Amplifier Core.....	10
Applications.....	1	Supply Connections	10
Functional Block Diagram	1	Output Clamping	10
General Description	1	Output Linearity.....	10
Revision History	2	Applications Information	11
Specifications.....	3	High-Side Current Sensing.....	11
Absolute Maximum Ratings.....	4	Motor Control Current Sensing.....	11
ESD Caution.....	4	Outline Dimensions	12
Pin Configuration and Function Descriptions.....	5	Ordering Guide	12
Typical Performance Characteristics	6		
Theory of Operation	10		

REVISION HISTORY

2/11—Rev. 0 to Rev. A	
Changes to Features Section.....	1
Changes to Amplifier Core Section	10
Moved Output Linearity Section into Theory of Operation Section.....	10
1/11—Revision 0: Initial Version	

SPECIFICATIONS

$T_{OPR} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $T_A = 25^{\circ}\text{C}$, $R_L = 25\text{ k}\Omega$, input common-mode voltage (V_{CM}) = 4 V (R_L is the output load resistor), unless otherwise noted.

Table 1.

Parameter	Min	Typ	Max	Unit	Test Conditions/Comments
GAIN					
Initial		60		V/V	$V_O \geq 0.1\text{ V dc}$, T_A
Accuracy		± 0.1		%	
Accuracy over Temperature			± 0.3	%	
Gain vs. Temperature		± 5		ppm/ $^{\circ}\text{C}$	
VOLTAGE OFFSET					
Offset Voltage (RTI ¹)			± 200	μV	25°C
Over Temperature (RTI ¹)			± 300	μV	T_{OPR}
Offset Drift		± 100		nV/ $^{\circ}\text{C}$	T_{OPR}
INPUT					
Bias Current ²		130	220	μA	T_A , input common mode = 4 V, $V_S = 4\text{ V}$
Common-Mode Input Voltage Range	4		80	μA	T_{OPR}
Differential Input Voltage Range ³	0		83	V	Common-mode continuous
Common-Mode Rejection (CMRR)	94	110		mV	Differential input voltage
				dB	T_{OPR}
OUTPUT					
Output Voltage Range Low ⁴	0.01			V	T_A
Output Voltage Range High ⁴			$V_S - 0.1$	V	T_A
Output Impedance		2		Ω	
DYNAMIC RESPONSE					
Small Signal –3 dB Bandwidth		500		kHz	
Slew Rate		1		V/ μs	
NOISE					
0.1 Hz to 10 Hz, (RTI ¹)		2.3		$\mu\text{V p-p}$	
Spectral Density, 1 kHz, (RTI ¹)		110		nV/ $\sqrt{\text{Hz}}$	
POWER SUPPLY					
Operating Range	4		80	V	V_S input range
Quiescent Current Over Temperature ⁵			800	μA	
Power Supply Rejection Ratio (PSRR)	100	110		dB	T_{OPR}
TEMPERATURE RANGE					
For Specified Performance	-40		$+125$	$^{\circ}\text{C}$	

¹ RTI = referred to input.

² Refer to Figure 8 for further information on the input bias current. This current varies based on the input common-mode voltage. Additionally, the input bias current flowing to the +IN pin is also the supply current to the internal LDO.

³ The differential input voltage is specified as 83 mV maximum because the output is internally clamped to 5.6 V. See the Output Clamping section.

⁴ See Figure 19 and Figure 20 for further information on the output range of the AD8219 with various loads. The AD8219 output clamps to a maximum voltage of 5.6 V when the voltage at Pin +IN is greater than 5.6 V. When the voltage at +IN is less than 5.6 V, the output reaches a maximum value of ($V_S - 100\text{ mV}$).

⁵ V_S (Pin 2) can be connected to a separate supply ranging from 4 V to 80 V, or it can be connected to the positive input pin (+IN) of the AD8219. In this mode, the current drawn varies with increasing voltage. See Figure 9.

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Maximum Input Voltage (+IN, –IN to GND)	–0.3 V to +85 V
Differential Input Voltage (+IN to –IN)	±5 V
Human Body Model (HBM) ESD Rating	±1000 V
Operating Temperature Range (T _{OPR})	–40°C to +125°C
Storage Temperature Range	–65°C to +150°C
Output Short-Circuit Duration	Indefinite

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

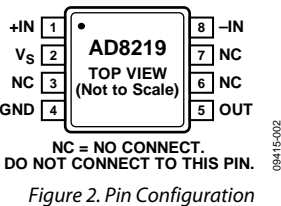


Table 3. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	+IN	Noninverting Input.
2	V _S	Supply Pin. Bypass with a standard 0.1 μ F capacitor.
3	NC	Do Not Connect to This Pin.
4	GND	Ground.
5	OUT	Output.
6	NC	Do Not Connect to This Pin.
7	NC	Do Not Connect to This Pin.
8	-IN	Inverting Input.

TYPICAL PERFORMANCE CHARACTERISTICS

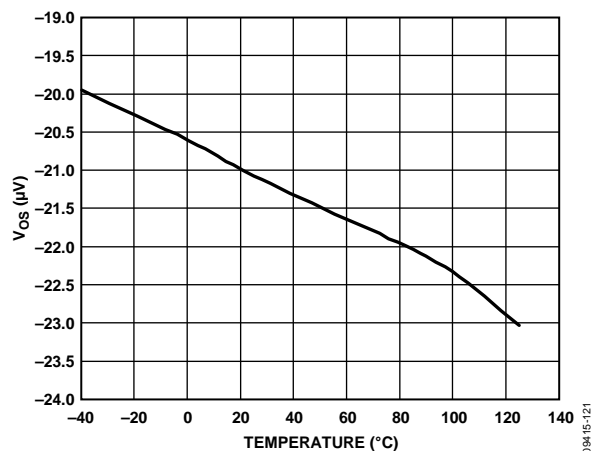


Figure 3. Typical Input Offset vs. Temperature

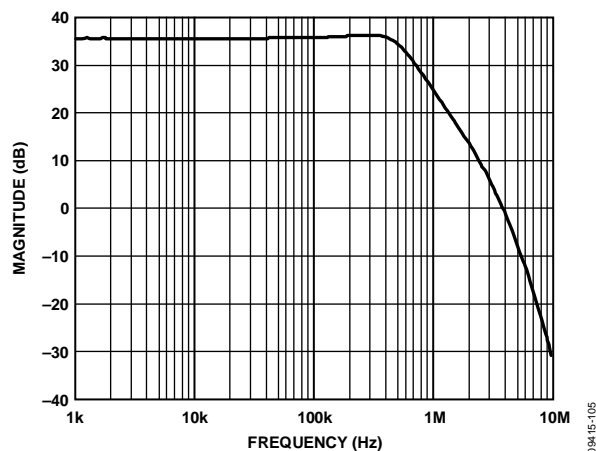
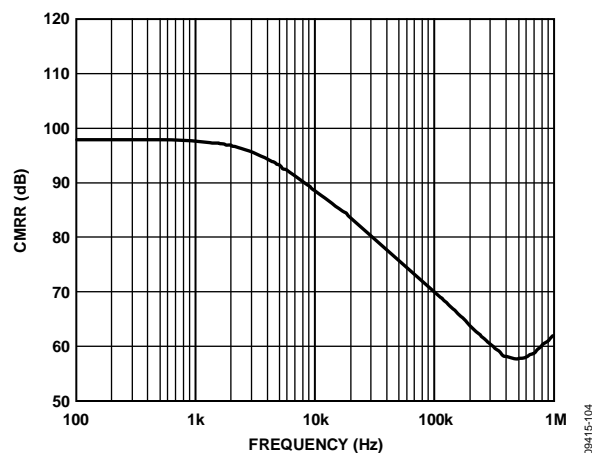
Figure 6. Typical Small Signal Bandwidth ($V_{OUT} = 200$ mV p-p)

Figure 4. Typical CMRR vs. Frequency

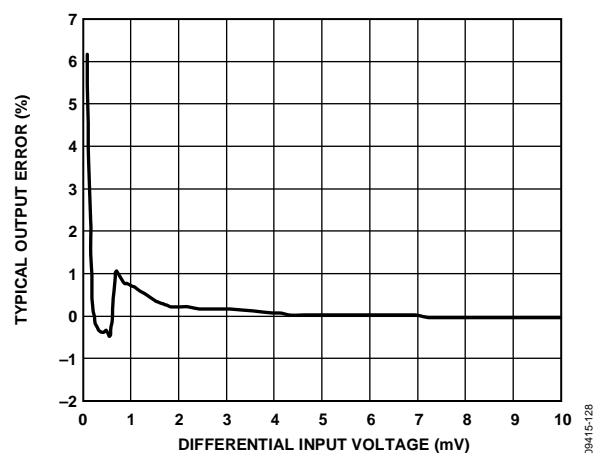


Figure 7. Typical Output Error vs. Differential Input Voltage

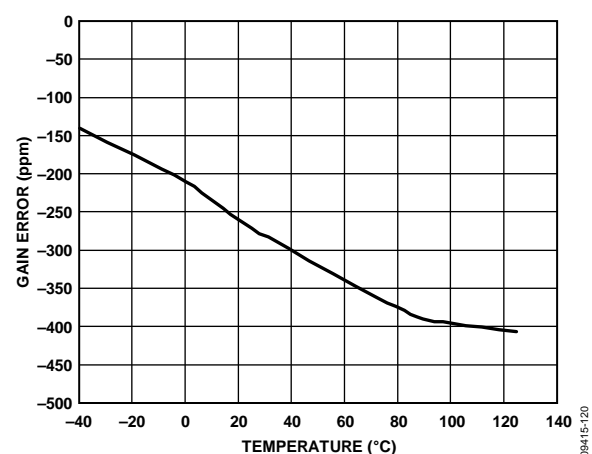
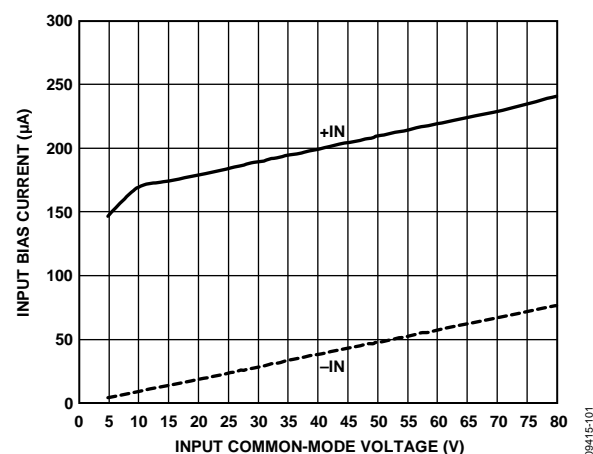


Figure 5. Typical Gain Error vs. Temperature

Figure 8. Input Bias Current vs. Input Common-Mode Voltage
(Differential Input Voltage = 5 mV) ($V_S = 5$ V)

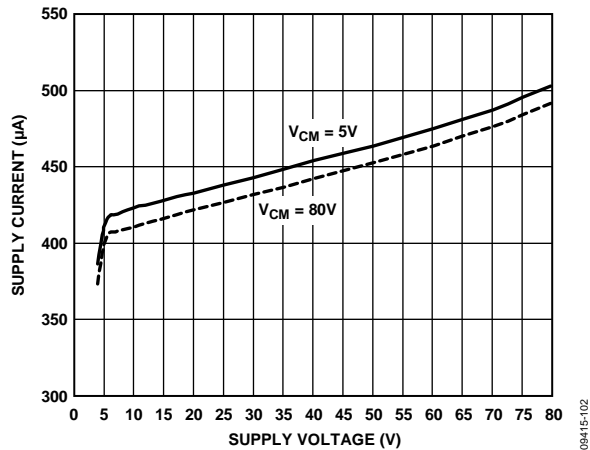


Figure 9. Typical Supply Current vs. Supply Voltage (V_S Connected to +IN)

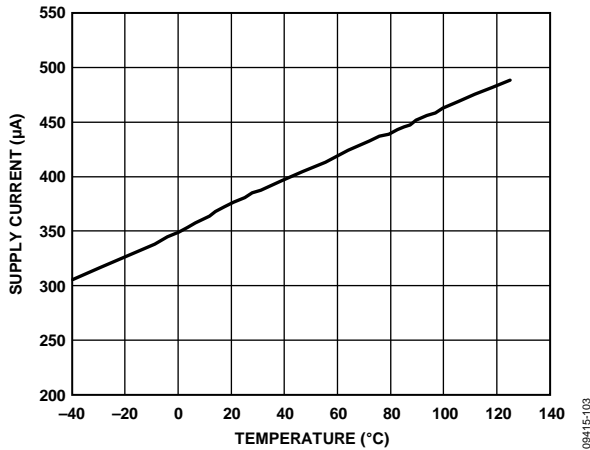


Figure 10. Typical Supply Current Change over Temperature ($V_S = 5 V$)

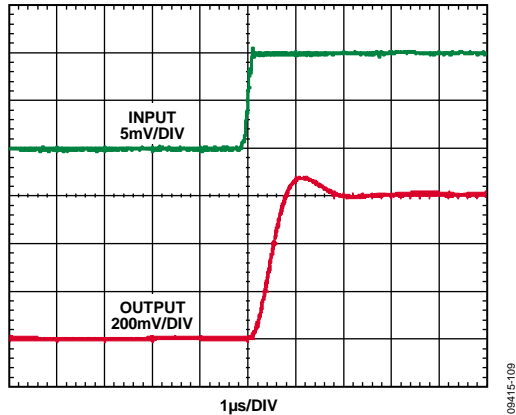


Figure 11. Rise Time (Differential Input = 5 mV)

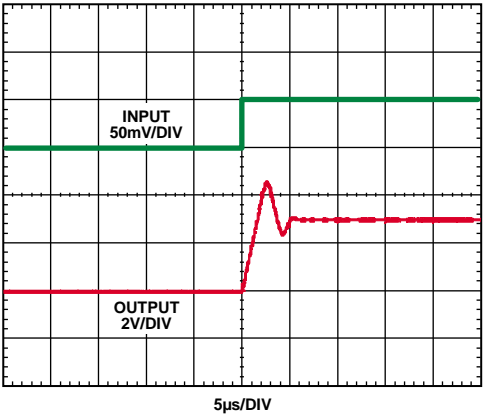


Figure 12. Rise Time (Differential Input = 50 mV)

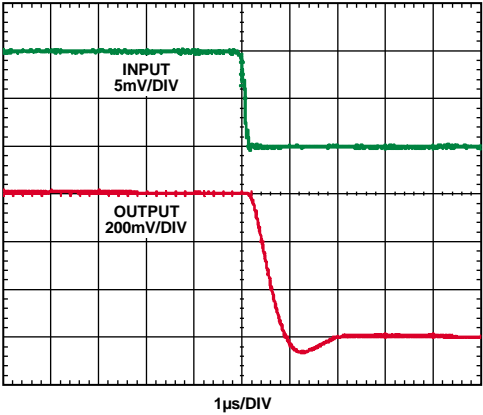


Figure 13. Fall Time (Differential Input = 5 mV)

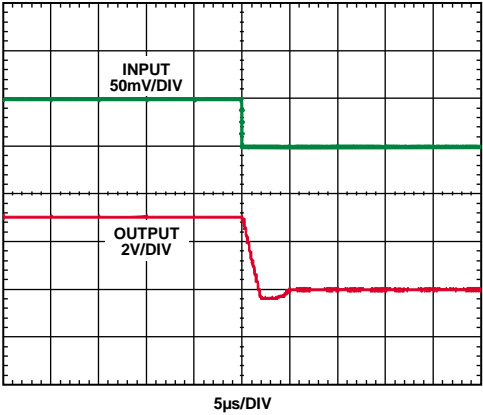


Figure 14. Fall Time (Differential Input = 50 mV)

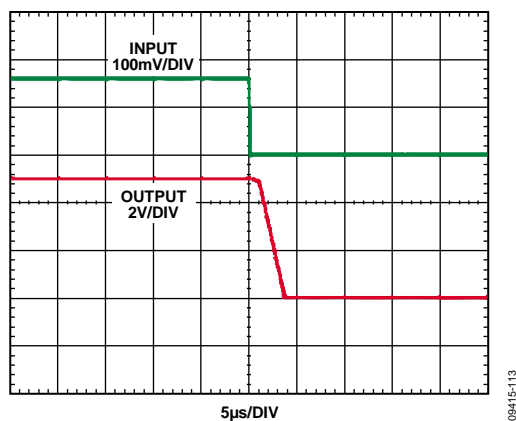


Figure 15. Differential Overload Recovery, Falling

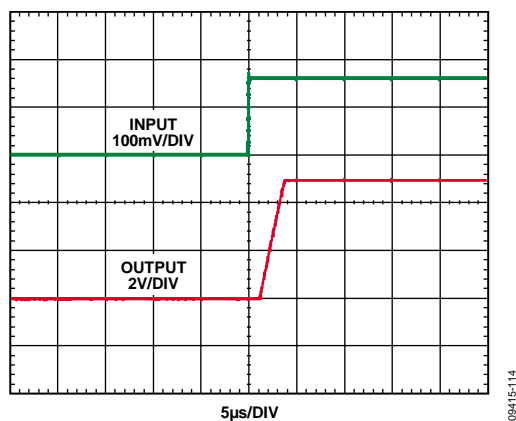


Figure 16. Differential Overload Recovery, Rising

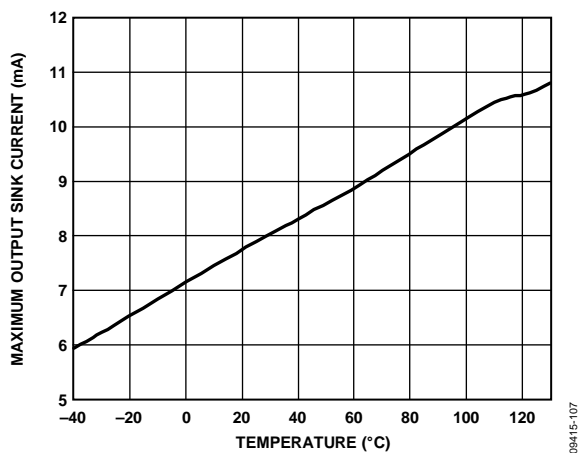


Figure 17. Maximum Output Sink Current vs. Temperature

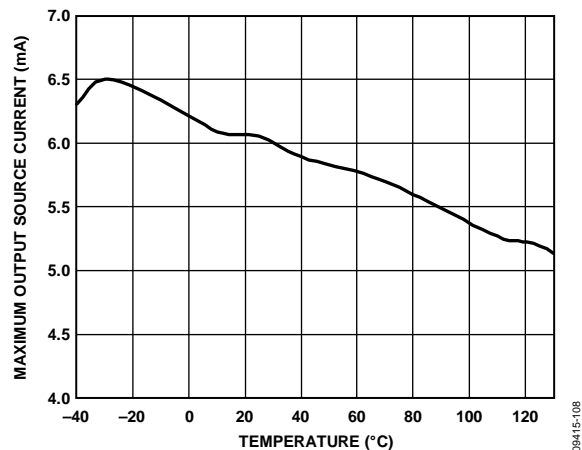
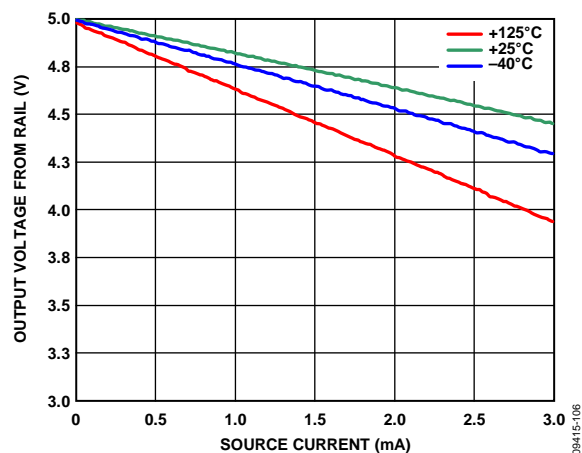
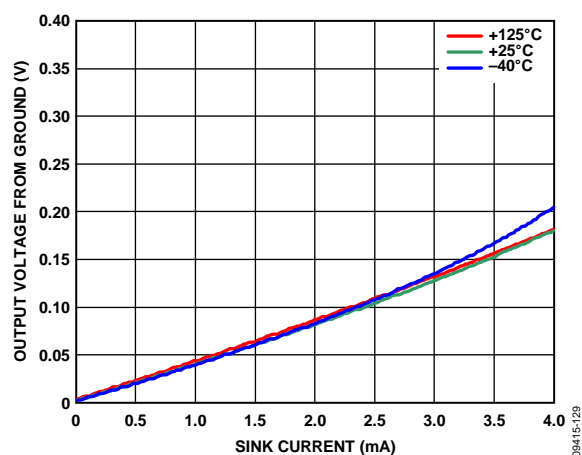


Figure 18. Maximum Output Source Current vs. Temperature

Figure 19. Output Voltage Range vs. Output Source Current ($V_S = 5\text{ V}$)Figure 20. Output Voltage Range From Ground vs. Output Sink Current ($V_S = 5\text{ V}$)

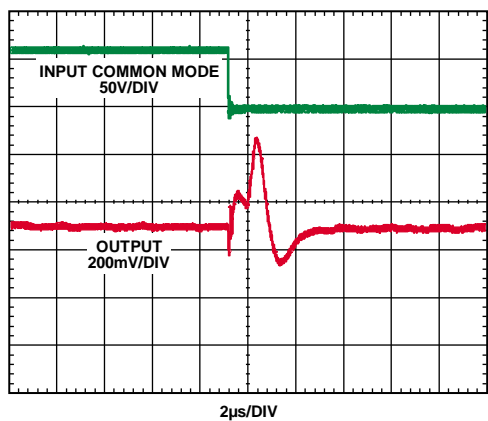


Figure 21. Common-Mode Step Response (Falling)

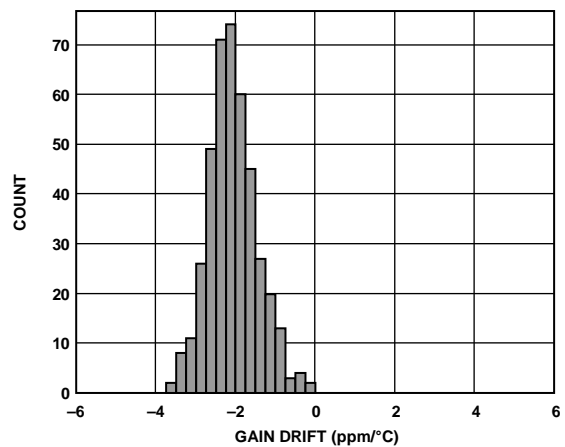


Figure 24. Gain Drift Distribution

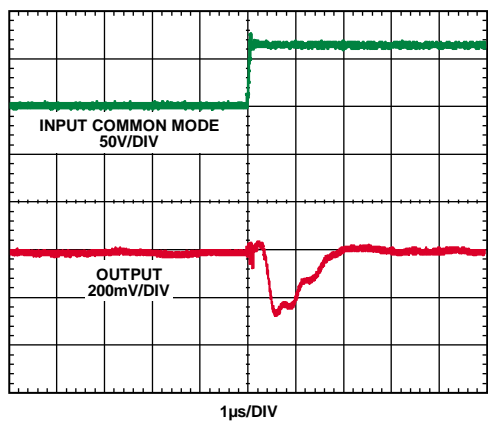


Figure 22. Common-Mode Step Response (Rising)

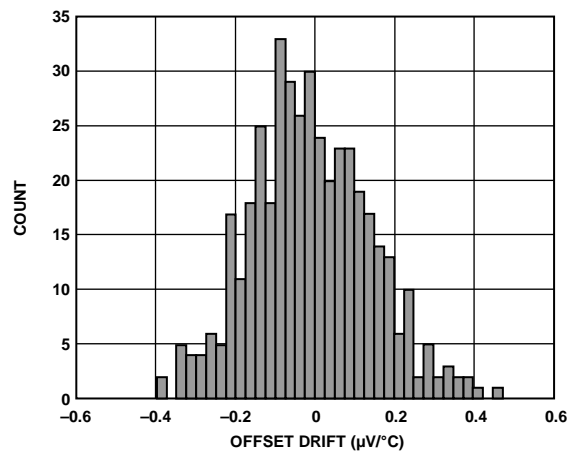


Figure 25. Input Offset Drift Distribution

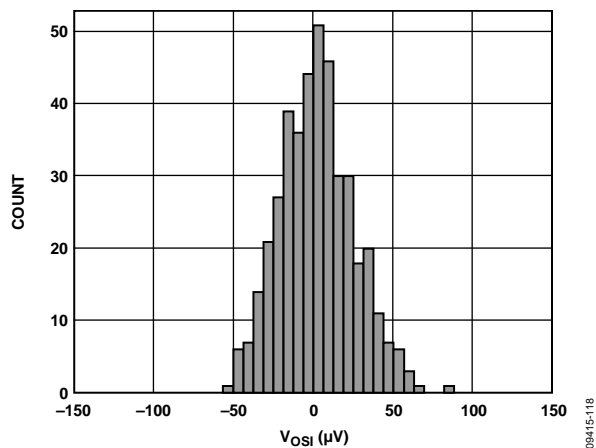


Figure 23. Input Offset Distribution

THEORY OF OPERATION

AMPLIFIER CORE

In typical applications, the AD8219 amplifies a small differential input voltage generated by the load current flowing through a shunt resistor. The AD8219 rejects high common-mode voltages (up to 80 V) and provides a ground referenced, buffered output that interfaces with an analog-to-digital converter (ADC). Figure 26 shows a simplified schematic of the AD8219.

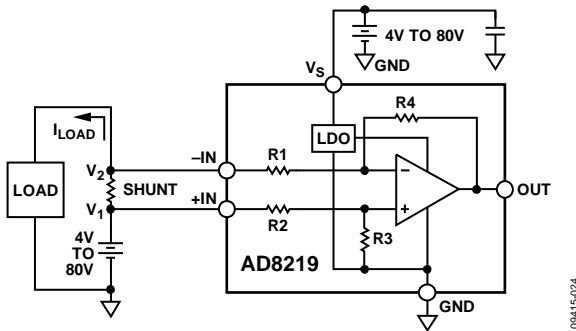


Figure 26. Simplified Schematic

The AD8219 is configured as a difference amplifier. The transfer function is

$$OUT = (R4/R1) \times (V_1 - V_2)$$

Resistors R4 and R1 are matched to within 0.01% and have values of 1.5 MΩ and 25 kΩ, respectively, meaning an input to output total gain of 60 V/V for the AD8219, while the difference at V₁ and V₂ is the voltage across the shunt resistor or V_{IN}. Therefore, the input-to-output transfer function for the AD8219 is

$$OUT = (60) \times (V_{IN})$$

The AD8219 accurately amplifies the input differential signal, rejecting high voltage common modes ranging from 4 V to 80 V.

The main amplifier uses a novel zero drift architecture, providing the end user with breakthrough temperature stability. The offset drift is typically less than ±100 nV/°C. This performance leads to optimal accuracy and dynamic range.

SUPPLY CONNECTIONS

The AD8219 includes an internal LDO, which allows the user to connect the V_s pin to the inputs, or use a separate supply at Pin 2 (V_s) to power the device. The input range of the supply pin is equivalent to the input common-mode range of 4 V to 80 V. The user must ensure that V_s is always connected to the +IN pin or a separate low impedance supply, which can range from 4 V to 80 V. The V_s pin should not be floating.

OUTPUT CLAMPING

When the input common-mode voltage in the application is above 5.6 V, the internal LDO output of the AD8219 also reaches its maximum value of 5.6 V, which is the maximum output range of the AD8219. Because in typical applications the output interfaces with a converter, clamping the AD8219 output voltage to 5.6 V ensures the ADC input is not damaged due to excessive overvoltage.

OUTPUT LINEARITY

In all current sensing applications where the common-mode voltage can vary significantly, it is important that the current sensor maintain the specified output linearity, regardless of the input differential or common-mode voltage. The AD8219 maintains a very high input-to-output linearity even when the differential input voltage is very small.

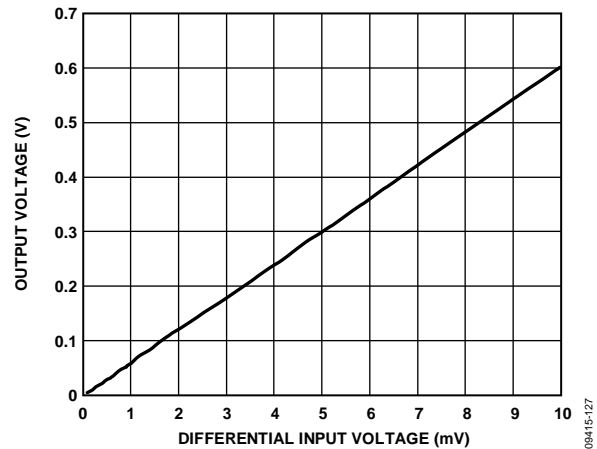


Figure 27. Typical Gain Linearity at Small Differential Inputs
(V_{CM} = 4 V to 80 V)

Regardless of the common mode, the AD8219 provides a correct output voltage when the input differential is at least 1 mV. The ability of the AD8219 to work with very small differential inputs, regardless of the common-mode voltage, allows for optimal dynamic range, accuracy, and flexibility in any current sensing application.

APPLICATIONS INFORMATION

HIGH-SIDE CURRENT SENSING

In this configuration, the shunt resistor is referenced to the battery (see Figure 28). High voltage is present at the inputs of the current sense amplifier. When the shunt is battery referenced, the AD8219 produces a linear ground referenced analog output.

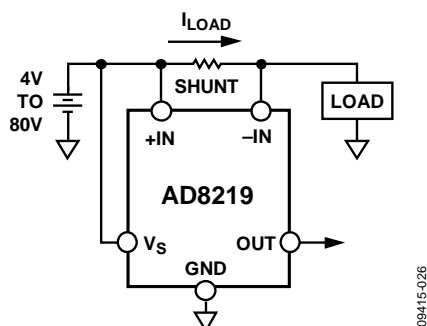


Figure 28. Battery Referenced Shunt Resistor

Figure 28 shows the supply pin, V_S , connected directly to the positive input (+IN) pin. In this mode, the internal LDO powers the AD8219 as long as the common-mode voltage at the input pins is 4 V to 80 V. Additionally, V_S can also be connected to a standalone supply that can vary from 4 V to 80 V as shown in Figure 29.

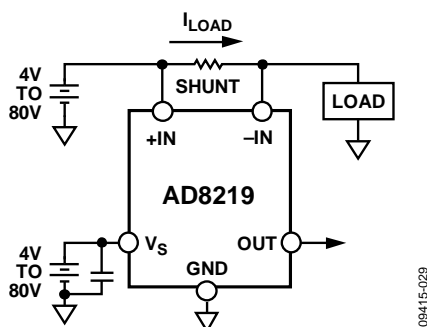


Figure 29. Standalone Supply Operation

MOTOR CONTROL CURRENT SENSING

The AD8219 is a practical, accurate solution for high-side current sensing in motor control applications. In cases where the shunt resistor is referenced to a battery and the current flowing is unidirectional (as shown in Figure 30), the AD8219 monitors the current with no additional supply pin necessary provided the battery voltage in the following circuit is in the 4 V to 80 V range.

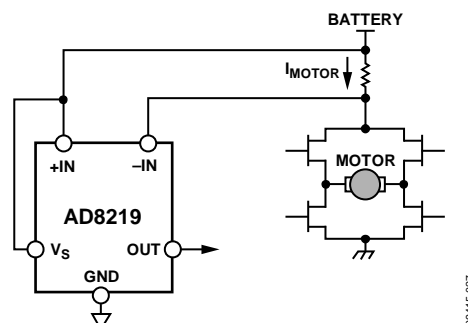
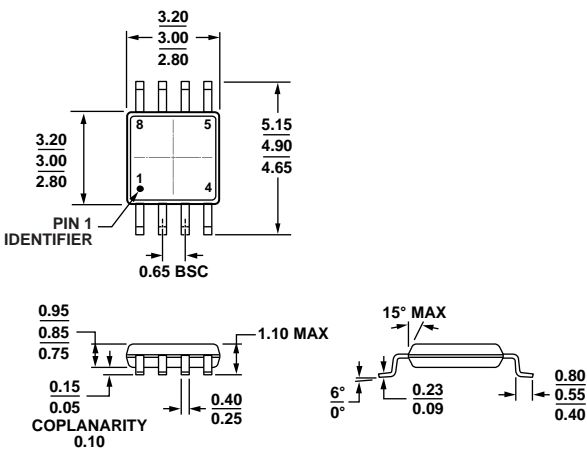


Figure 30. High-Side Current Sensing in Motor Control

OUTLINE DIMENSIONS



ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Branding
AD8219BRMZ	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	Y3S
AD8219BRMZ-RL	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	Y3S

¹ Z = RoHS Compliant Part.